

SN74AUP2G80

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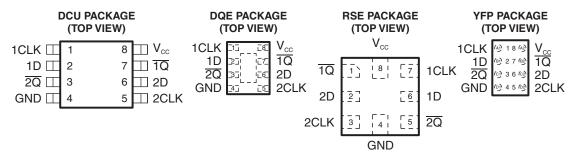
LOW-POWER DUAL POSITIVE-EDGE-TRIGGERED D-TYPE FLIP-FLOP

Check for Samples: SN74AUP2G80

FEATURES

- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption (I_{CC} = 0.9 μA Maximum)
- Low Dynamic-Power Consumption (C_{pd} = 4.3 pF Typ at 3.3 V)
- Low Input Capacitance (C_i = 1.5 pF Typical)
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- I_{off} Supports Partial-Power-Down Mode Operation
- Wide Operating V_{CC} Range of 0.8 V to 3.6 V

- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- t_{pd} = 4.4 ns Maximum at 3.3 V
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in Figure 2).

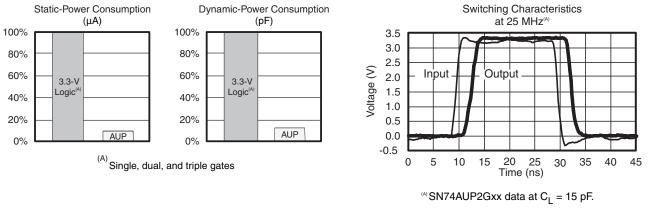




Figure 2. Excellent Signal Integrity

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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TEXAS INSTRUMENTS

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When data at the data (D) input meets the setup time requirement, the data is transferred to the Q output on the positive-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold-time interval, data at the D input can be changed without affecting the levels at the outputs.

NanoStar[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YFP (Pb-free)	Reel of 3000	SN74AUP2G80YFPR	H X _
-40°C to 85°C	uQFN – DQE	Reel of 5000	SN74AUP2G80DQER	PU
	QFN – RSE	Reel of 5000	SN74AUP2G80RSER	PU
	SSOP – DCU	Reel of 3000	SN74AUP2G80DCUR	H80_

ORDERING INFORMATION⁽¹⁾

For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

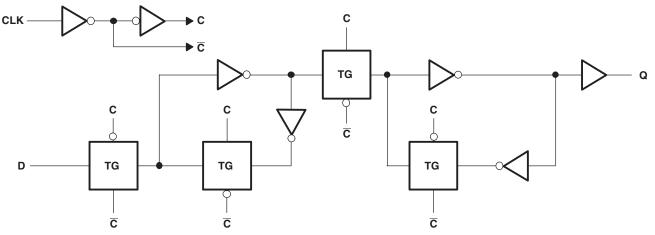
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(3) DCU: The actual top-side marking has one additional character that designates the wafer fab/assembly site. YFP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

FUNCTION TABLE

INPU	JTS	OUTPUT
CLK	D	Q
Ť	Н	L
↑	L	Н
L	Х	Q ₀

LOGIC DIAGRAM (POSITIVE LOGIC)



Pin numbers shown are for the DCU and DQE packages.



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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage range ⁽²⁾		-0.5	4.6	V
Vo	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾		-0.5	4.6	V
Vo	Output voltage range in the high or low stat	e ⁽²⁾	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current			±20	mA
	Continuous current through V_{CC} or GND			±50	mA
		DCU package		220	
0	Decline the result interaction (3)	DQE package		261	°C/W
θ_{JA}	Package thermal impedance ⁽³⁾	RSE package		253	-0/10
		YFP package		-50 ±20 ±50 220 261	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.



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INSTRUMENTS

Texas

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		0.8	3.6	V
		$V_{CC} = 0.8 V$	V _{CC}		
v		V_{CC} = 1.1 V to 1.95 V	$0.65 \times V_{CC}$		V
VIH	High-level input voltage	V_{CC} = 2.3 V to 2.7 V	1.6		v
		V_{CC} = 3 V to 3.6 V	2		
		$V_{CC} = 0.8 V$		0	
		V_{CC} = 1.1 V to 1.95 V		$0.35 \times V_{CC}$	V
VIL	Low-level input voltage	V_{CC} = 2.3 V to 2.7 V		0.7	v
		V_{CC} = 3 V to 3.6 V		0.9	
VI	Input voltage		0	3.6	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 0.8 V		-20	μA
	High-level output current	V _{CC} = 1.1 V		-1.1	
		$V_{CC} = 1.4 V$		-1.7	
I _{OH}		V _{CC} = 1.65		-1.9	mA
		$V_{CC} = 2.3 V$		-3.1	
		V _{CC} = 3 V		-4	
		V _{CC} = 0.8 V		20	μA
		V _{CC} = 1.1 V		1.1	
		V _{CC} = 1.4 V		1.7 1.9 3.1	
I _{OL}	Low-level output current	V _{CC} = 1.65 V			
		V _{CC} = 2.3 V			
		$V_{CC} = 3 V$		4	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 0.8 V \text{ to } 3.6 V$		200	ns/V
T _A	Operating free-air temperature	+	-40	85	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED		N N	TA	= 25°C	$T_A = -40^{\circ}$	T _A = -40°C to 85°C		
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP MA	X MIN	MAX	UNIT	
	I _{OH} = -20 μA	0.8 V to 3.6 V	V _{CC} – 0.1		V _{CC} - 0.1			
	I _{OH} = -1.1 mA	1.1 V	0.75 × V _{CC}		0.7 × V _{CC}			
	I _{OH} = -1.7 mA	1.4 V	1.11		1.03			
	I _{OH} = -1.9 mA	1.65 V	1.32		1.3			
V _{OH}	I _{OH} = -2.3 mA	0.0.1/	2.05		1.97		V	
	I _{OH} = -3.1 mA	2.3 V	1.9		1.85			
	I _{OH} = -2.7 mA	0.14	2.72		2.67			
	I _{OH} = -4 mA	3 V	2.6		2.55			
	I _{OL} = 20 μA	0.8 V to 3.6 V		0	.1	0.1		
	I _{OL} = 1.1 mA	1.1 V		0.3 × V _C	C	$0.3 \times V_{CC}$	V	
	I _{OL} = 1.7 mA	1.4 V		0.3	51	0.37		
N/	I _{OL} = 1.9 mA	1.65 V		0.3	1	0.35		
VOL	I _{OL} = 2.3 mA	221/		0.3	51	0.33		
	I _{OL} = 3.1 mA	2.3 V		0.4	4	0.45		
	I _{OL} = 2.7 mA			0.3	1	0.33		
$V_{OH} = \frac{1.1 \text{ mA}}{10H} = -1.1 \text{ mA}} = \frac{1.1 \text{ V}}{1.4 \text{ V}}$ $\frac{1_{OH} = -1.7 \text{ mA}}{1.4 \text{ V}} = 1.4 \text{ V}}$ $\frac{1_{OH} = -1.9 \text{ mA}}{1.65 \text{ V}} = 1.4 \text{ V}}$ $\frac{1_{OH} = -2.3 \text{ mA}}{1_{OH} = -3.1 \text{ mA}} = 2.3 \text{ V}}$ $\frac{1_{OH} = -2.7 \text{ mA}}{1_{OH} = -4 \text{ mA}} = 3 \text{ V}}$ $\frac{1_{OH} = -4 \text{ mA}}{1_{OH} = -4 \text{ mA}} = 0.8 \text{ V to } 3.6 \text{ V}}$ $\frac{1_{OL} = 20 \mu \text{ A}}{1_{OL} = 20 \mu \text{ A}} = 0.8 \text{ V to } 3.6 \text{ V}}$ $\frac{1_{OL} = 1.1 \text{ mA}}{1.1 \text{ V}} = 1.7 \text{ mA}} = 1.4 \text{ V}}$ $\frac{1_{OL} = 1.7 \text{ mA}}{1_{OL} = 1.7 \text{ mA}} = 1.4 \text{ V}}$ $\frac{1_{OL} = 1.9 \text{ mA}}{1_{OL} = 2.3 \text{ mA}} = 2.3 \text{ V}}$ $\frac{1_{OL} = 3.1 \text{ mA}}{1_{OL} = 2.7 \text{ mA}} = 3 \text{ V}}$ $\frac{1_{OL} = 3.1 \text{ mA}}{1_{OL} = 2.7 \text{ mA}} = 3 \text{ V}}$ $\frac{1_{OL} = 4 \text{ mA}}{1_{OL} = 4 \text{ mA}} = 3 \text{ V}}$ $\frac{1_{I} \text{ A or B input V}_{I} = \text{GND to } 3.6 \text{ V}}{0 \text{ V to } 3.6 \text{ V}} = 0 \text{ V to } 3.6 \text{ V}}$ $\frac{1_{I} \text{ A or B input V}_{I} = \text{GND or } (V_{CC} \text{ to } 3.6 \text{ V}), 0.8 \text{ V to } 3.6 \text{ V}}$ $\frac{1_{OL} = 0}{100} = 0 \text{ V}$ $\frac{1_{OL} = 0}{100} = 0 \text{ V}$ $\frac{1_{OL} = 0}{100} = 0 \text{ V}$		0.4	4	0.45				
II A or B input	$V_I = GND$ to 3.6 V	0 V to 3.6 V		0	.1	0.5	μΑ	
l _{off}	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}$	0 V		0	2	0.6	μΑ	
ΔI _{off}	V_{I} or V_{O} = 0 V to 3.6 V	0 V to 0.2 V		0	2	0.6	μA	
Icc	(V _{CC} to 3.6 V),	0.8 V to 3.6 V		0	5	0.9	μΑ	
ΔI _{CC}		3.3 V		4	0	50	μA	
<u> </u>	V = V or CND	0 V		1.5			۶Ē	
Ui		3.6 V		1.5			pF	
Co	V _O = GND	0 V		3			pF	

(1) One input at V_{CC} – 0.6 V, other input at V_{CC} or GND



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TIMING REQUIREMENTS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

			V _{cc}	T _A = 25°C	T _A = -4 to 85	0°C °C	UNIT
				ТҮР	MIN	MAX	-
			0.8 V			20	
			1.2 V ± 0.1 V			80	
ſ			1.5 V ± 0.1 V			120	N 41 I
f _{clock}	Clock frequency		1.8 V ± 0.15 V			160	MHz
			2.5 V ± 0.2 V			220	
			3.3 V ± 0.3 V			260	
			0.8 V		5.5		
			1.2 V ± 0.1 V		2.5		
	Dulas duration Objective		1.5 V ± 0.1 V		1.5		
t _w	Pulse duration, CLK high or lo	W	1.8 V ± 0.15 V		1.6		
			2.5 V ± 0.2 V		1.7		
			3.3 V ± 0.3 V		1.9		
			0.8 V	3.4	6.7		
			1.2 V ± 0.1 V		2.4		
		1.5 V ± 0.1 V		1.2			
		Data high	1.8 V ± 0.15 V		0.8		ns
			2.5 V ± 0.2 V		0.6		
			3.3 V ± 0.3 V		0.4		
t _{su}	Setup time before CLK↑		0.8 V	3.4	8.9		
			1.2 V ± 0.1 V		2		
		Data law	1.5 V ± 0.1 V		1.3		
		Data low	1.8 V ± 0.15 V		1.1		ns
			2.5 V ± 0.2 V		0.8		
			3.3 V ± 0.3 V		0.7		
			0.8 V	0	1		
			1.2 V ± 0.1 V		0		
			1.5 V ± 0.1 V		0		
t _h	Hold time, data after CLK↑		1.8 V ± 0.15 V		0		ns
'n			2.5 V ± 0.2 V		0		
			3.3 V ± 0.3 V		0		



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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 5 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	TO (OUTPUT)	V _{cc}	T _A = 25°C			T _A = -40°C to 85°C		UNIT
	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	
			0.8 V		91		90		
			1.2 V ± 0.1 V		175		220		
4			1.5 V ± 0.1 V		237		230		N 41 1-
f _{max}			1.8 V ± 0.15 V		269		240		MHz
			2.5 V ± 0.2 V		280		250		
			3.3 V ± 0.3 V		280		260		
			0.8 V		17.2				
			1.2 V ± 0.1 V	3.2	7.1	14.9	2.7	16.3	
4		ā	1.5 V ± 0.1 V	1.9	5	9.8	2.1	10.3	
t _{pd}	CLK	Q	1.8 V ± 0.15 V	1.7	3.9	7.6	1.6	8.1	ns
		2.5 V ± 0.2 V	1.4	2.8	5.3	1.2	5.6		
			3.3 V ± 0.3 V	1.2	2.2	4.1	1	4.4	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 10 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{cc}	Т	ק = 25°C		T _A = to 85		UNIT
		(OUTPUT)		MIN	TYP	MAX	MIN	MAX	
			0.8 V		68		70		
			1.2 V ± 0.1 V		128		170		
4			1.5 V ± 0.1 V		189		220		MHz
f _{max}			1.8 V ± 0.15 V		234		240		IVITIZ
			2.5 V ± 0.2 V		273		250		
			3.3 V ± 0.3 V		280		260		
			0.8 V		19.4				
			1.2 V ± 0.1 V	4.4	8.2	16.2	3.4	17.7	
		ā	1.5 V ± 0.1 V	3.6	5.8	10.7	2.6	11.3	
t _{pd}	CLK	Q	1.8 V ± 0.15 V	2.9	4.6	8.4	2.1	3	ns
			2.5 V ± 0.2 V	2.2	3.3	5.9	1.7	6.3	
			3.3 V ± 0.3 V	1.9	2.7	4.7	1.4	4.9	



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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM		V _{cc}	т,	₄ = 25°C		T _A = to 85		UNIT
	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	
			0.8 V		52		50		
			1.2 V ± 0.1 V		98		130		
4			1.5 V ± 0.1 V		148		180		MHz
f _{max}			1.8 V ± 0.15 V		196		240		IVIEZ
			2.5 V ± 0.2 V		249		250		
			3.3 V ± 0.3 V		280		260		
			0.8 V		21.5				
			1.2 V ± 0.1 V	3	9.1	17.4	4.1	19	
		Q	1.5 V ± 0.1 V	3.2	6.5	11.7	3.2	12.3	
t _{pd}	CLK	Q	1.8 V ± 0.15 V	2.7	4.2	9.2	2.6	9.8	ns
			2.5 V ± 0.2 V	2.2	3.8	6.5	2.1	6.9	
			3.3 V ± 0.3 V	1.9	3.1	5.1	1.8	5.5	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM (INPUT)	TO	V _{cc}	т,	₄ = 25°C		T _A = to 85		UNIT
	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	
			0.8 V		32		20		
			1.2 V ± 0.1 V		71		80		
4			1.5 V ± 0.1 V		104		120		MHz
f _{max}			1.8 V ± 0.15 V		133		160		WHZ
			2.5 V ± 0.2 V		181		220		
			3.3 V ± 0.3 V		257		260		
			0.8 V		28.4				
			1.2 V ± 0.1 V	5.1	11.8	20.7	6.2	28.7	
		ā	1.5 V ± 0.1 V	4.8	8.5	14.1	6.9	16.7	
t _{pd}	CLK	Q	1.8 V ± 0.15 V	4	6.9	11.2	2	13.3	ns
			2.5 V ± 0.2 V	3.3	5.1	7.9	3.2	9.3	
			3.3 V ± 0.3 V	2.9	4.2	6.4	2.8	7.5	

OPERATING CHARACTERISTICS

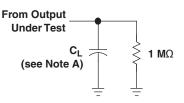
 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
			0.8 V	4	
			1.2 V ± 0.1 V	4	
<u> </u>	Dower discipation conscitution	f 10 MU	1.5 V ± 0.1 V	4 4 0.1 V 4 0.1 V 4 1.1 V 4 0.1 V 4 0.2 V 4.1	. F
C _{pd}	Power dissipation capacitance	f = 10 MHz	1.8 V ± 0.15 V		pF
			2.5 V ± 0.2 V	4.1	_
			3.3 V ± 0.3 V		

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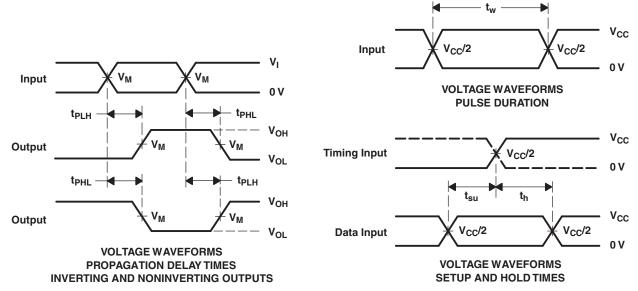
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PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Width)



	V _{CC} = 0.8 V			V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V_{CC} = 3.3 V ± 0.3 V	
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	
VI	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	

LOAD CIRCUIT



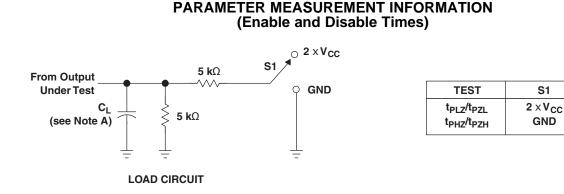
- Α. C_L includes probe and jig capacitance.
- Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output Β. control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_D = 50 Ω , for propagation delays $t_r/t_f = 3$ ns, for setup and hold times and pulse width $t_r/t_f = 1.2$ ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- Ε. t_{PLH} and t_{PHL} are the same as t_{pd} .
- F. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

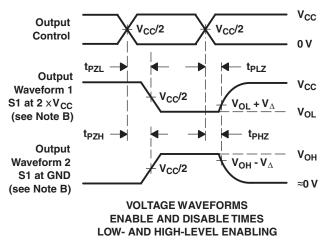


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	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V_{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	$V_{CC} = 3.3 \text{ V}$ $\pm 0.3 \text{ V}$
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
VM	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
VI	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V_{Δ}	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_r/t_f = 3 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PLH} and t_{PHL} are the same as t_{pd} .
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms



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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SN74AUP2G80DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74AUP2G80DQER	ACTIVE	X2SON	DQE	8	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74AUP2G80RSER	ACTIVE	UQFN	RSE	8	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74AUP2G80YFPR	ACTIVE	DSBGA	YFP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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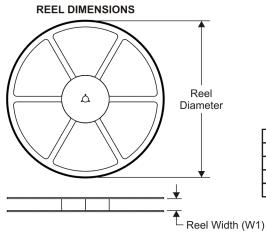
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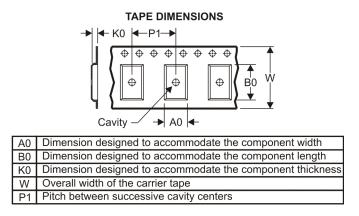
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal Device	1	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP2G80DCUR	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74AUP2G80DQER	X2SON	DQE	8	5000	180.0	8.4	1.17	1.67	0.73	4.0	8.0	Q1
SN74AUP2G80RSER	UQFN	RSE	8	5000	180.0	8.4	1.6	1.6	0.66	4.0	8.0	Q2
SN74AUP2G80YFPR	DSBGA	YFP	8	3000	178.0	9.2	0.9	1.75	0.6	4.0	8.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

6-May-2011



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP2G80DCUR	US8	DCU	8	3000	202.0	201.0	28.0
SN74AUP2G80DQER	X2SON	DQE	8	5000	202.0	201.0	28.0
SN74AUP2G80RSER	UQFN	RSE	8	5000	202.0	201.0	28.0
SN74AUP2G80YFPR	DSBGA	YFP	8	3000	220.0	220.0	35.0

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.

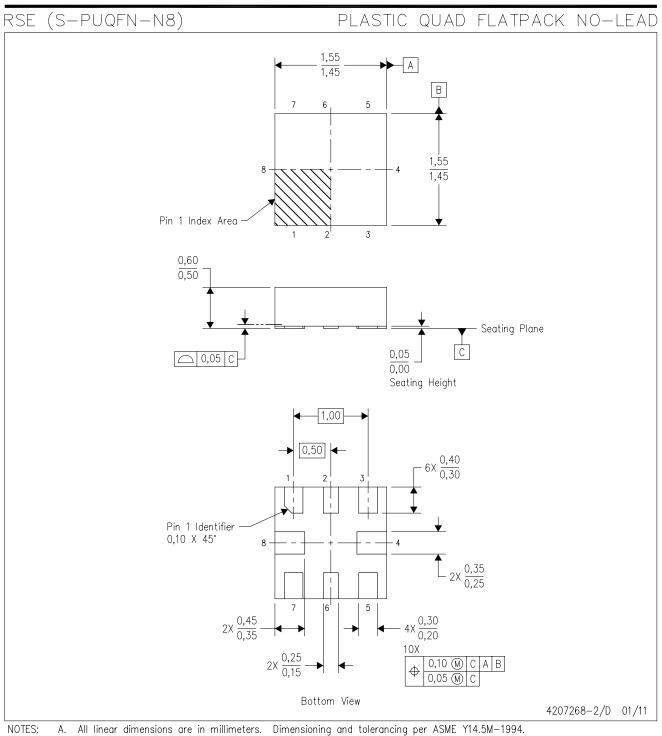




- NOTES: A. All linear dimensions are in millimeters. В. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

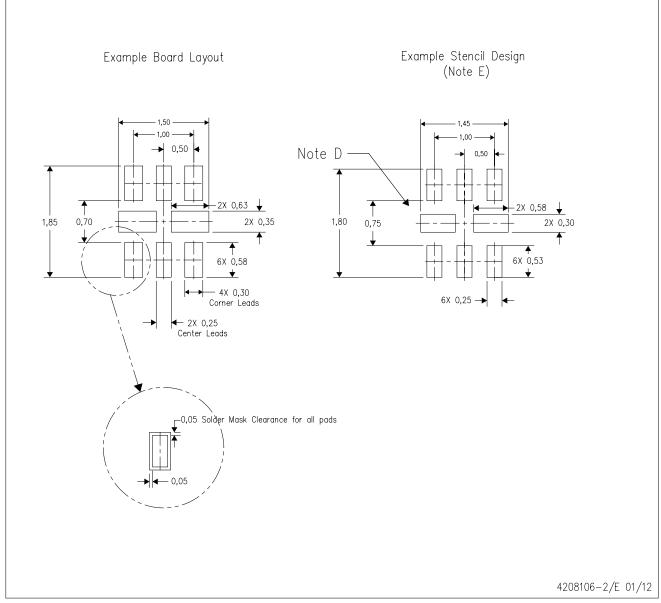


B. This drawing is subject to change without notice.
C. QFN (Quad Flatpack No-Lead) package configuration.
D. This package complies to JEDEC MO-288 variation UECD.



RSE (S-PUQFN-N8)

PLASTIC QUAD FLATPACK NO-LEAD

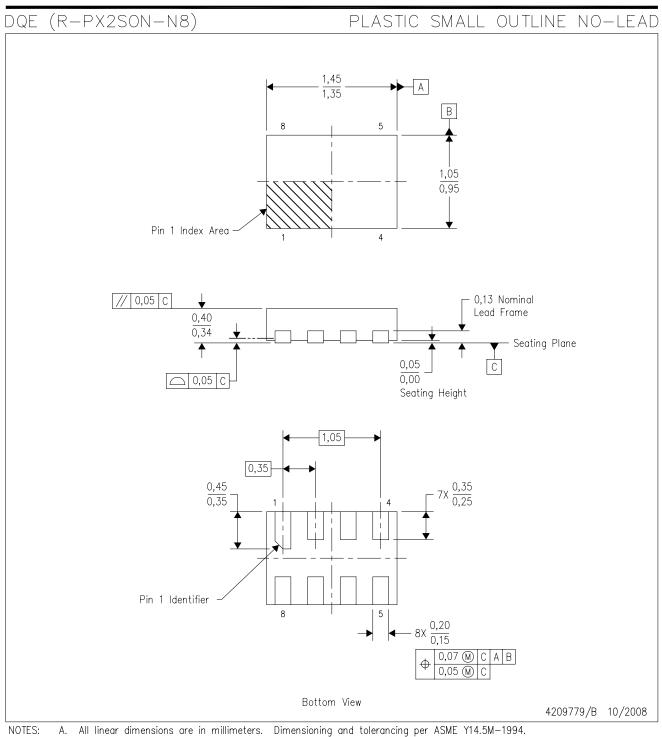


NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication $\mathsf{IPC-7351}$ is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.

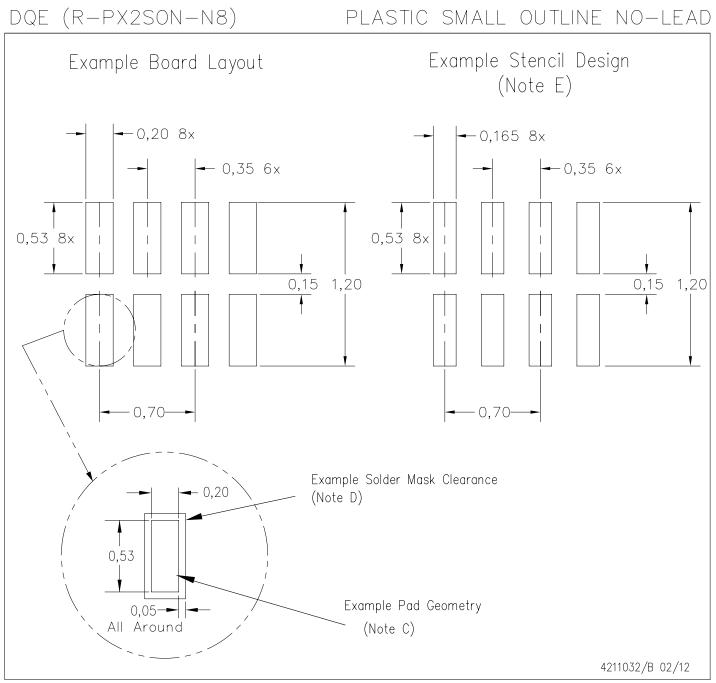


MECHANICAL DATA



- B. This drawing is subject to change without notice.
 C. SON (Small Outline No-Lead) package configuration.
 D. This package complies to JEDEC M0-287 variation X2EAF.





NOTES: A. All linear dimensions are in millimeters.

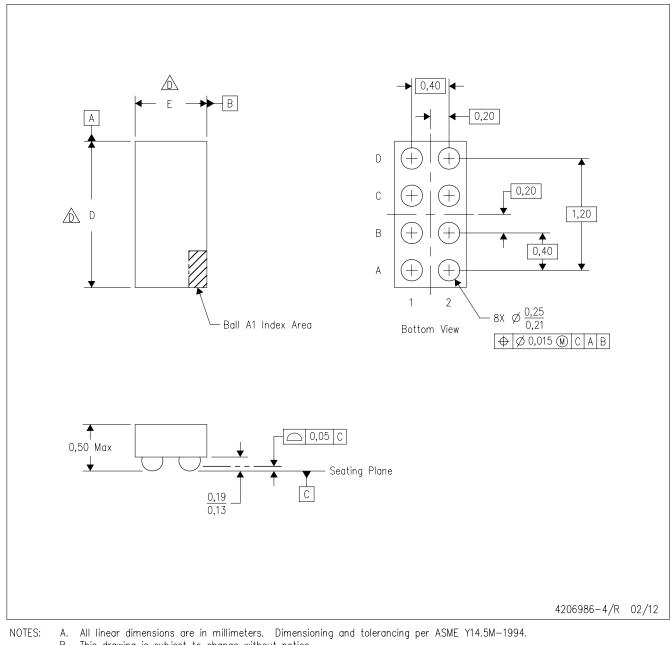
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Over-printing land for acceptable area ratio is not viable due to land width and bridging potential. Customer may further reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.
- H. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- I. Component placement force should be minimized to prevent excessive paste block deformation.



MECHANICAL DATA

YFP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version of this drawing, in case it cannot be found in the product data sheet please contact a local TI representative.
- E. Reference Product Data Sheet for array population. 2 x 4 matrix pattern is shown for illustration only.
- F. This package contains Pb-free balls.

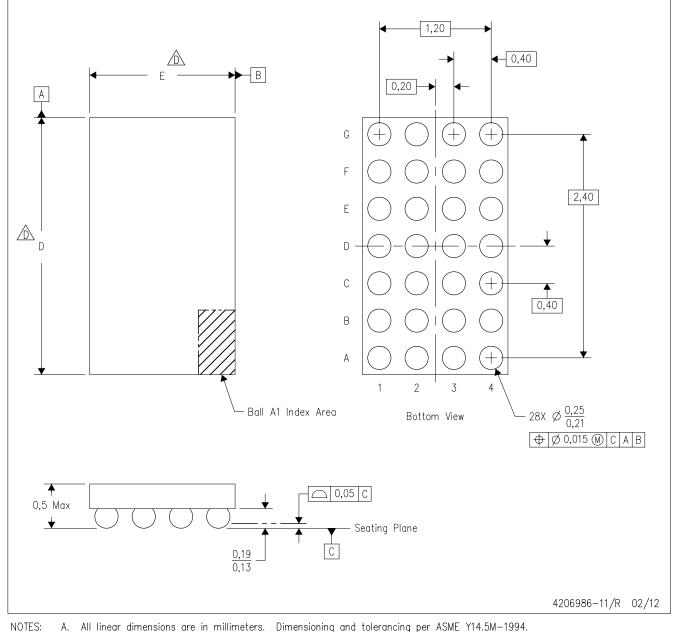
NanoFree is a trademark of Texas Instruments



MECHANICAL DATA

YFP (R-XBGA-N28)

DIE-SIZE BALL GRID ARRAY



- This drawing is subject to change without notice. Β.
- NanoFree™ package configuration. C.
- To determine the exact package size of a particular device, refer to the device datasheet or contact a local TI representative. D.
- E. This package contains Pb-free balls.

NanoFree is a trademark of Texas Instruments



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